

SIPMOS®- Kleinsignaltransistoren

Bedrahtete Bauformen

SIPMOS® Small-Signal Transistors

Leaded types

Typ Type	$V_{DS(max)}$ V	$V_{GS(th)}$ V	$I_{D(max)}$ mA	$R_{DS(on)max}$ Ω	P_{tot} mW	Bestellnummer Ordering code	Gehäuse Package	Bild Figure
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N-Kanal-Anreicherungstypen

N channel enhancement types

BSS 98	50	0.8 ... 1.6	300	3.5	630	Q62702-S464	TO-92	2a, 3a
BSS 295	50	0.8 ... 2.0	1400	0.3	1000	Q62702-S603	TO-92	2b, 3b
BS 170	60	0.8 ... 2.0	300	5	630	Q67000-S061	TO-92	2a, 3a
SN 7000	60	0.8 ... 2.0	250	5	630	Q67000-S062	TO-92	2c, 3c
BSS 100	100	0.8 ... 2.0	220	6	630	Q62702-S483	TO-92	2a, 3a
BSS 296	100	0.8 ... 2.0	800	0.8	1000	Q62702-S615	TO-92	2b, 3b
BS 107	200	0.8 ... 2.0	130	26	1000	Q67000-S060	TO-92	2a, 3a
BSS 297	200	0.8 ... 2.0	480	2	1000	Q62702-S616	TO-92	2b, 3b
BSS 88	240	0.6 ... 1.2	250	8	1000	Q62702-S454	TO-92	2b, 3b
BSS 89	240	0.8 ... 2.0	290	6	1000	Q62702-S455	TO-92	2b, 3b
BSS 101	240	0.8 ... 2.0	130	16	630	Q62702-S484	TO-92	2a, 3a
BSS 124	400	1.5 ... 2.5	120	28	1000	Q62702-S614	TO-92	2a, 3a
BSS 125	600	1.5 ... 2.5	100	45	1000	Q62702-S505	TO-92	2b, 3b

P-Kanal-Anreicherungstypen

P channel enhancement types

BSS 110	-50	-0.8 ... -2.0	-170	10	630	Q62702-S489	TO-92	2a, 3a
SP 0610 L	-60	-1.0 ... -2.0	-180	10	630	Q67000-S065	TO-92	2c, 3c
BSS 92	-240	-0.8 ... -2.0	-150	20	1000	Q62702-S458	TO-92	2b, 3b

N-Kanal-Verarmungstypen

N channel depletion types

BSS 149	200	<-0.7	350	3.5	1000	Q62702-S623	TO-92	2b, 3b
BSS 129	240	<-0.7	150	20	1000	Q62702-S510	TO-92	2b, 3b
BSS 229	250	<-0.7	70	100	630	Q62702-S567	TO-92	2b, 3b
BSS 135	600	<-0.7	80	60	1000	Q62702-S601	TO-92	2b, 3b